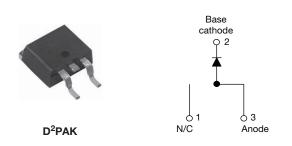
### **Vishay Semiconductors**

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High Performance Schottky Rectifier, 19 A



PRODUCT SUMMARY	
Package	D <sup>2</sup> PAK
I <sub>F(AV)</sub>	19 A
V <sub>R</sub>	15 V
V <sub>F</sub> at I <sub>F</sub>	0.36 V
I <sub>RM</sub> max.	522 mA at 100 °C
T <sub>J</sub> max.	125 °C
Diode variation	Single die
E <sub>AS</sub>	6.75 mJ

### FEATURES

- 125 °C T<sub>J</sub> operation ( $V_R < 5 V$ )
- · Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The VS-19TQ015SPbF Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS A	ND CHARACTERISTICS		
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I <sub>F(AV)</sub>	Rectangular waveform	19	A
V <sub>RRM</sub>		15	V
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	700	A
V <sub>F</sub>	19 A <sub>pk</sub> , T <sub>J</sub> = 75 °C	0.32	V
TJ	Range	-55 to +125	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-19TQ015SPbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	15	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	10	V

ABSOLUTE MAXIMUM RA	TINGS				
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_{C}$ = 80 °C, rectangular waveform		19	А
Maximum peak one cycle non-repetitive surge current	less s	5 µs sine or 3 µs rect. pulse Following any rated load condition and with		700	А
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	330	~
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L = 6 mH		6.75	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 3 x V <sub>R</sub> typical		1.50	A

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ELECTRICAL SPECIFICATIONS
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ELECTRICAL SPECIFICATI	ONS				
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		19 A	19 A T <sub>1</sub> = 25 °C		
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	38 A	1j=25 C	0.46	V
		19 A	T 75 00	0.32	
		38 A	- T <sub>J</sub> = 75 °C	0.43	
	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 100 °C, V <sub>R</sub> = 12 V		465	
Maximum reverse leakage current See fig. 2		$T_{J} = 100 \text{ °C}, V_{R} = 5 \text{ V}$		285	
		T <sub>J</sub> = 25 °C		10.5	mA
		T <sub>J</sub> = 100 °C	V <sub>R</sub> = Rated V <sub>R</sub>	522	
Maximum junction capacitance	CT	$V_{R}$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		2000	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temper	ature range	TJ		-55 to +125	°C
Maximum storage temper	ature range	T <sub>Stg</sub>		-55 to +150	U
Maximum thermal resistar junction to case	ice,	R <sub>thJC</sub>	DC operation See fig. 4	1.50	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	0/11
Approximate weight				2	g
				0.07	oz.
Mar allocations a	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style D <sup>2</sup> PAK	19TQ	015S

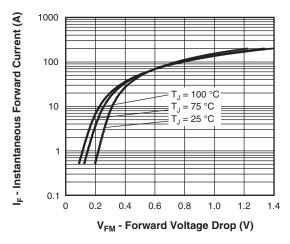


Fig. 1 - Maximum Forward Voltage Drop Characteristics

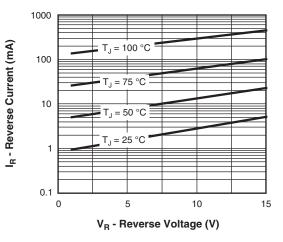


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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# VS-19TQ015SPbF

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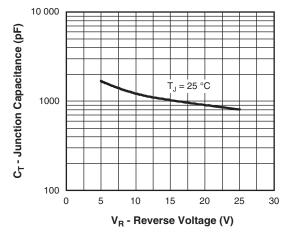


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

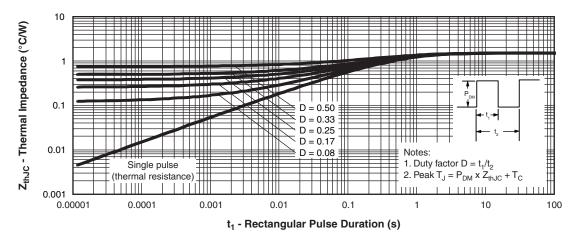
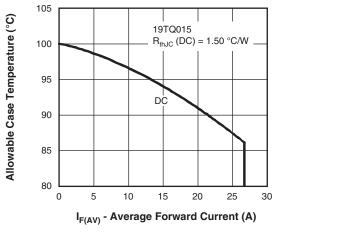


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





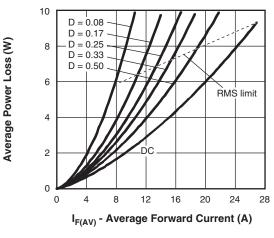


Fig. 6 - Forward Power Loss Characteristics

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# VS-19TQ015SPbF

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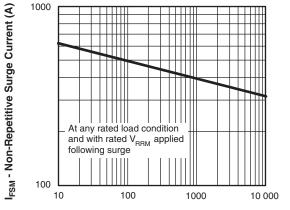




Fig. 7 - Maximum Non-Repetitive Surge Current

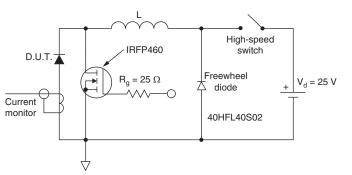


Fig. 8 - Unclamped Inductive Test Circuit

### **ORDERING INFORMATION TABLE**

**Device code** VS-19 Т 015 S TRL PbF Q (2) (3) (4) (5) (6)(7)(1)(8) 1 Vishay Semiconductors product 2 Current rating (19 A) 3 Circuit configuration: T = TO-220 4 Schottky "Q" series 5 Voltage rating (015 = 15 V) 6  $S = D^2 PAK$ \_ 7 • None = tube (50 pieces) • TRL = tape and reel (left oriented) • TRR = tape and reel (right oriented)

8 - PbF = lead (Pb)-free

LINKS TO RELA	TED DOCUMENTS
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?96005

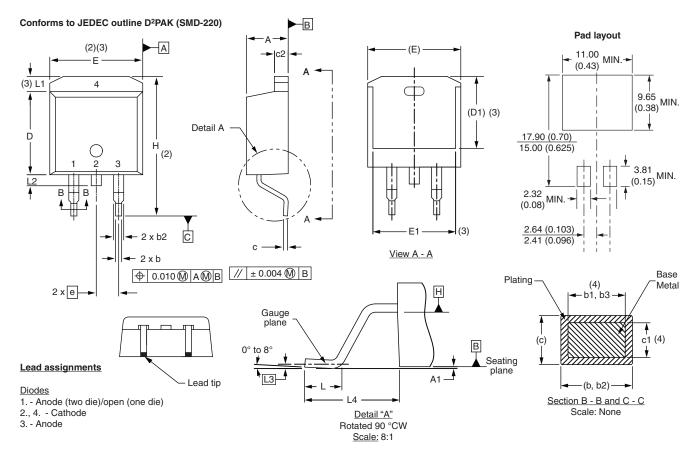
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**Vishay Semiconductors** 

# D<sup>2</sup>PAK, TO-262



#### DIMENSIONS - D<sup>2</sup>PAK in millimeters and inches

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SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS INCHES	HES	NOTES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

(7) Outline conforms to JEDEC outline TO-263AB

#### Notes

- $^{(1)}\,$  Dimensioning and tolerancing per ASME Y14.5 M-1994  $\,$
- <sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

Document Number: 95014	For
Revision: 31-Mar-09	Diodes

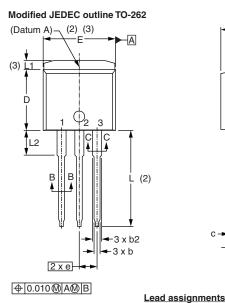
# **Outline Dimensions**

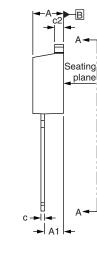
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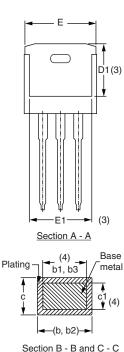
D<sup>2</sup>PAK, TO-262



#### **DIMENSIONS - TO-262** in millimeters and inches







Section B - B and C - C

Lead tip Scale: None MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 4.06 4.83 0.160 0.190 А A1 2.03 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 0.51 0.89 0.020 0.035 4 b1 h2 1.14 1.78 0.045 0.070 b3 1.14 1.73 0.045 0.068 4 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 0.045 0.065 c2 1.65 D 8.51 9.65 0.335 0.380 2 0.270 D1 6.86 8.00 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 е 2.54 BSC 0.100 BSC L 13.46 14.10 0.530 0.555 L1 1.65 0.065 \_ 3 L2 3.56 3.71 0.140 0.146

1. - Anode (two die)/open (one die)

Diodes

3. - Anode

2., 4. - Cathode

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

(minimum) and D1 (minimum) where dimensions derived the actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b

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